

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,056,809 B2
APPLICATION NO. : 10/695938
DATED : June 6, 2006
INVENTOR(S) : Rayssac

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 10:

Line 28 (claim 6, line 2), after "the plasma are Si and SF₆, SiC and SF₆/O₂," insert
-- SiO₂ --.

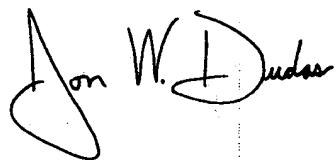
Line 58 (claim 14, line 5), after "clusters that is directed to" delete "is directed to".

Column 11:

Line 9 (claim 17, line 4), after "controlled number of" delete "ion sin" and insert -- ions
in --.

Signed and Sealed this

Twenty-seventh Day of March, 2007



JON W. DUDAS
Director of the United States Patent and Trademark Office